NSN 5961-01-185-9966

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-185-9966 **Inclosure Material:** Glass **Overall Length:** Between 0.220 inches and 0.300 inches **Overall Diameter:** Between 0.108 inches and 0.140 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 400.00 milliamperes forward current, average absolute and 3.00 amperes forward current, average preset **Special Features:** Insulated wires with tab terminals **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No